



RELIABILITY REPORT FOR MAX6497ATA+

PLASTIC ENCAPSULATED DEVICES

June 17, 2009

## MAXIM INTEGRATED PRODUCTS

120 SAN GABRIEL DR. SUNNYVALE, CA 94086

Approved by
Ken Wendel
Quality Assurance
Director, Reliability Engineering



#### Conclusion

The MAX6497ATA+ successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

#### **Table of Contents**

IDevice Description	VQuality Assurance Information
IIManufacturing Information	VIReliability Evaluation
IIIPackaging Information	IVDie Information

- I. Device Description
  - A. General

.....Attachments

The MAX6495-MAX6499 is a family of small, low-current, overvoltage-protection circuits for high-voltage transient systems such as those found in automotive and industrial applications. These devices monitor the input voltage and control an external n-channel MOSFET switch to isolate the load at the output during an input overvoltage condition. The MAX6495-MAX6499 operate over a wide supply voltage range from +5.5V to +72V.

The gate of the n-channel MOSFET is driven high while the monitored input is below the user-adjustable overvoltage threshold. An integrated chargepump circuit provides a 10V gate-to-source voltage to fully enhance the n-channel MOSFET. When the input voltage exceeds the user-adjusted overvoltage threshold, the gate of the MOSFET is quickly pulled low, disconnecting the load from the input. In some applications, disconnecting the output from the load is not desirable. In these cases, the protection circuit can be configured to act as a voltage limiter where the GATE output sawtooths to limit the voltage to the load (MAX6495/MAX6496/MAX6499).

The MAX6496 supports lower input voltages and reduces power loss by replacing the external reverse battery diode with an external series p-channel MOSFET. The MAX6496 generates the proper bias voltage to ensure that the p-channel MOSFET is on during normal operations. The gate-to-source voltage is clamped during load-dump conditions, and the p-channel MOSFET is off during reverse-battery conditions.

The MAX6497/MAX6498 feature an open-drain, undedicated comparator that notifies the system if the output falls below the programmed threshold. The MAX6497 keeps the MOSFET switch latched off until either the input power or the active-low SHDN pin is cycled. The MAX6498 will autoretry when VOVSET falls below 130mV. These devices are available in small, thermally enhanced, 6-pin and 8-pin TDFN packages and are fully specified from -40°C to +125°C.



## II. Manufacturing Information

A. Description/Function:	72V, Overvoltage-Protection Switches/Limiter Controllers with an External MOSFET
B. Process:	BCD8
C. Number of Device Transistors:	566
D. Fabrication Location:	Oregon
E. Assembly Location:	Philippines, Thailand, Malaysia
F. Date of Initial Production:	July 23, 2005

## III. Packaging Information

A. Package Type:	8-pin TDFN 3x3
B. Lead Frame:	Copper
C. Lead Finish:	100% matte Tin
D. Die Attach:	Conductive Epoxy
E. Bondwire:	Gold (1 mil dia.)
F. Mold Material:	Epoxy with silica filler
G. Assembly Diagram:	#05-9000-1748
H. Flammability Rating:	Class UL94-V0
I. Classification of Moisture Sensitivity per JEDEC standard J-STD-020-C	Level 1
J. Single Layer Theta Ja:	54°C/W
K. Single Layer Theta Jc:	8.3°C/W
L. Multi Layer Theta Ja:	41°C/W
M. Multi Layer Theta Jc:	8.3°C/W

## IV. Die Information

A. Dimensions:	61 X 75 mils
B. Passivation:	Si <sub>3</sub> N <sub>4</sub> /SiO <sub>2</sub> (Silicon nitride/ Silicon dioxide
C. Interconnect:	Al/0.5% Cu
D. Backside Metallization:	None
E. Minimum Metal Width:	3.0 microns (as drawn)
F. Minimum Metal Spacing:	3.0 microns (as drawn)
G. Bondpad Dimensions:	5 mil. Sq.
H. Isolation Dielectric:	SiO <sub>2</sub>
I. Die Separation Method:	Wafer Saw



#### V. Quality Assurance Information

A. Quality Assurance Contacts:	Ken Wendel (Director, Reliability Engineering) Bryan Preeshl (Managing Director of QA)
B. Outgoing Inspection Level:	<ul><li>0.1% for all electrical parameters guaranteed by the Datasheet.</li><li>0.1% For all Visual Defects.</li></ul>
C. Observed Outgoing Defect Rate:	< 50 ppm
D. Sampling Plan:	Mil-Std-105D

#### VI. Reliability Evaluation

#### A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in Table 1. Using these results, the Failure Rate ( $\lambda$ ) is calculated as follows:

 $\lambda = \underbrace{1}_{MTTF} = \underbrace{1.83}_{192 \text{ x } 4340 \text{ x } 96 \text{ x } 2} (\text{Chi square value for MTTF upper limit}) \\ (\text{where } 4340 \text{ = Temperature Acceleration factor assuming an activation energy of 0.8eV}) \\ \lambda = 11.2 \text{ x } 10^{.9} \\ \lambda = 11.2 \text{ F.I.T. (60\% confidence level @ 25°C)}$ 

The following failure rate represents data collected from Maxim's reliability monitor program. Maxim performs quarterly 1000 hour life test monitors on its processes. This data is published in the Product Reliability Report found at http://www.maxim-ic.com/. Current monitor data for the BCD88 Process results in a FIT Rate of 3.92 @ 25C and 47.44 @ 55C (0.8 eV, 60% UCL)

#### B. Moisture Resistance Tests

The industry standard 85°C/85%RH or HAST testing is monitored per device process once a quarter.

#### C. E.S.D. and Latch-Up Testing

The MS93-1 die type has been found to have all pins able to withstand a HBM transient pulse of 2500 per JEDEC JESD22-A114-D. Latch-Up testing has shown that this device withstands a current of 250.



# Table 1 Reliability Evaluation Test Results

## MAX6497ATA+

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES	
Static Life Test	(Note 1)				
	Ta = 135°C	DC Parameters	96	0	
	Biased	& functionality			
	Time = 192 hrs.				
Moisture Testing	(Note 2)				
85/85	Ta = 85°C	DC Parameters	77	0	
	RH = 85%	& functionality			
	Biased				
	Time = 1000hrs.				
Mechanical Stres	ss (Note 2)				
Temperature	-65°C/150°C	DC Parameters	77	0	
Cycle	1000 Cycles	& functionality			
-	Method 1010				

Note 1: Life Test Data may represent plastic DIP qualification lots.

Note 2: Generic Package/Process data